Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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MOS FIELD EFFECT POWER TRANSISTOR 2SK1286

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK1286 is N-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

FEATURES

Low On-state Resistance

RDS(on) \leq 70 m Ω (VGS = 10 V, ID = 8 A) RDS(on) \leq 95 m Ω (VGS = 4 V, ID = 8 A)

- Low Ciss Ciss = 1 400 pF TYP.
- Built-in G-S Gate Protection Diodes

QUALITY GRADE

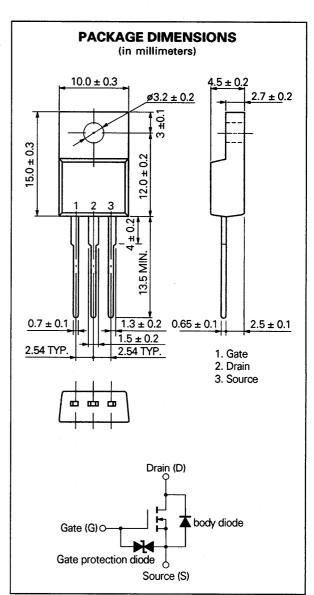
Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Drain to Source Voltage	Voss	60	V
Gate to Source Voltage	VGSS(AC	±20	٧
Drain Current (DC)	ID(DC)	±15	Α
Drain Current (pulse)	D(pulse)	* ±60	Α
Total Power Dissipation (Ta = 25 °C)	P _{T1}	2.0	W
Total Power Dissipation (Tc = 25 °C)	Рт2	30	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C

^{*} PW \leq 10 μ s, Duty Cycle \leq 1 %

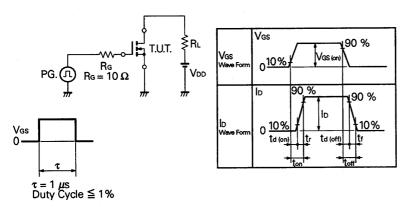




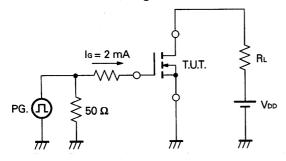
ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	Ros(on)		55	70	mΩ	Vgs = 10 V, ID = 8 A
Drain to Source On-state Resistance	Ros(on)		80	95	mΩ	Vgs = 4.0 V, lp = 8 A
Gate to Source Cutoff Voltage	Vgs(off)	1.0		2.5	V	Vos = 10 V, lo = 1 mA
Forward Transfer Admittance	y fs	7.0	14		s	Vos = 10 V, lo = 8 A
Drain Leakage Current	loss			10	μΑ	Vps = 60 V, Vgs = 0
Gate to Source Leakage Current	lgss			±10	μΑ	Vgs = ±20 V, Vps = 0
Input Capacitance	Ciss		1 400		pF	V _{DS} = 10 V V _{GS} = 0 f = 1 MHz
Output Capacitance	Coss		500		pF	
Reverse Transfer Capacitance	Crss		130		pF	
Turn-On Delay Time	td(on)		25		ns	$V_{GS(on)} = 10 \text{ V}$ $V_{DD} = 30 \text{ V}$ $I_D = 10 \text{ A}, R_G = 10 \Omega$ $R_L = 3.0 \Omega$
Rise Time	tr		160		ns	
Turn-Off Delay Time	td(off)		130		ns	
Fall Time	tr		80		ns	
Total Gate Charge	Qg		30		nC	V _S = 10 V I _D = 20 A V _{DD} = 48 V
Gate to Source Charge	Qgs		5		nC	
Gate to Drain Charge	Qgp		10		nC	
Diode Forward Voltage	Vsp		1.0		V	Iso = 15 A, Vgs = 0
Reverse Recovery Time	trr		150		ns	IF = 20 A, VGS = 0
Reverse Recovery Charge	Qrr		250		nC	di/dt = 50 A/μs

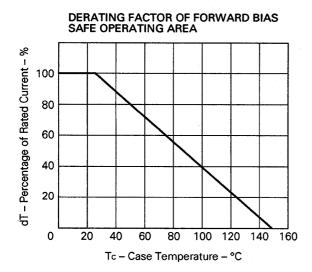
Test Circuit 1: Switching Time

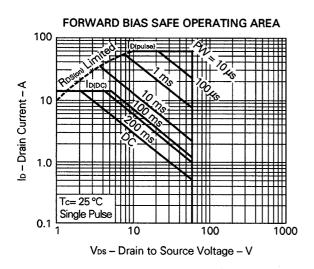


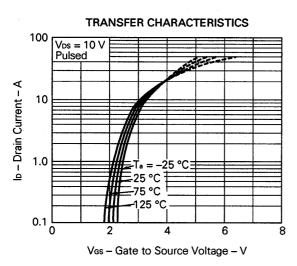
Test Circuit 2: Gate Charge

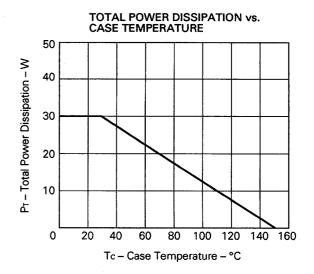


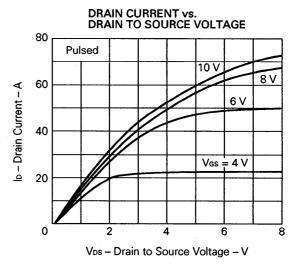
TYPICAL CHARACTERISTICS (Ta = 25 °C)

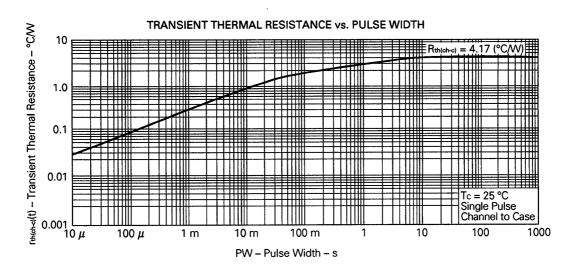


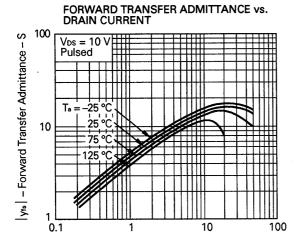


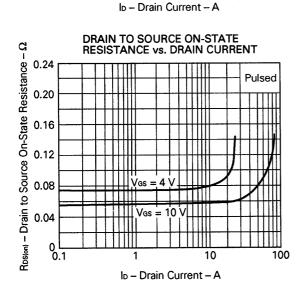


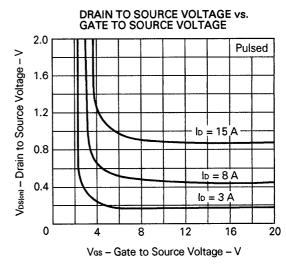


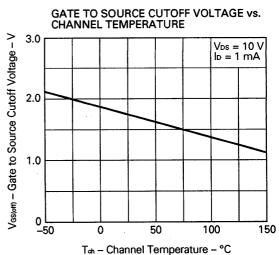




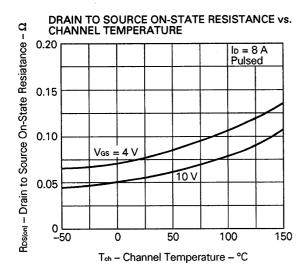


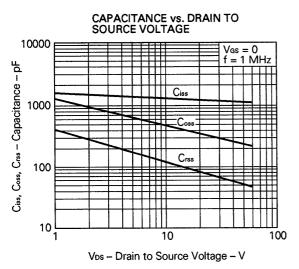


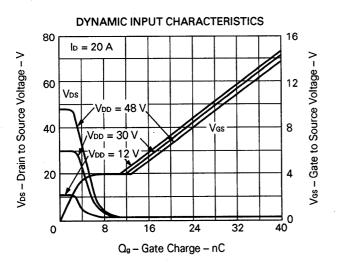


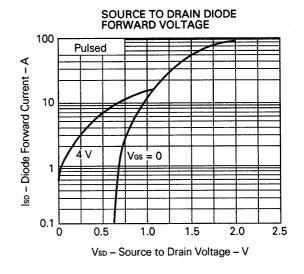


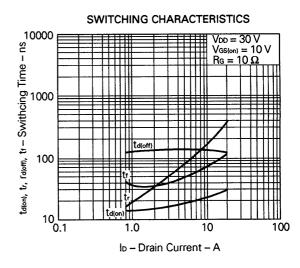
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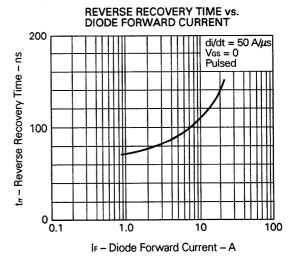














Reference

Application note name	No.
Safe operating area of Power MOS FET.	TEA-1034
Application circuit using Power MOS FET.	TEA-1035
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207

[MEMO]

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